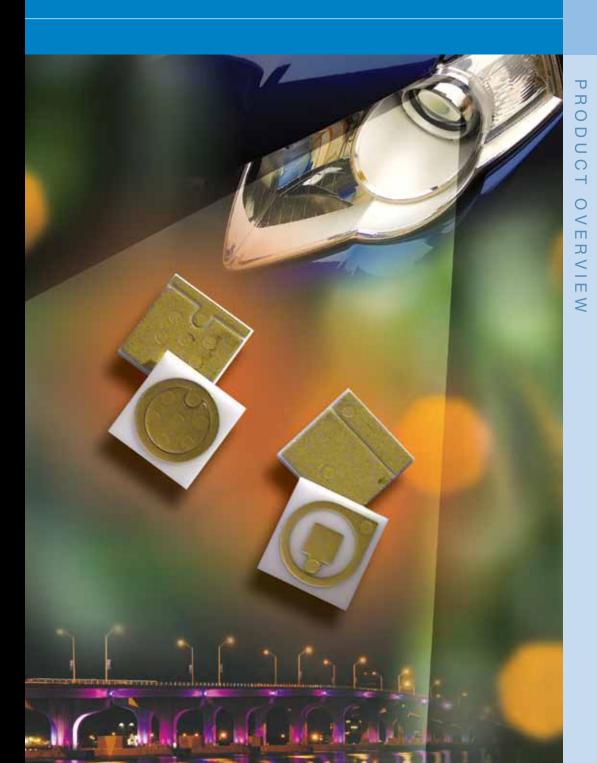


# **CERAMIC THIN FILM LED PACKAGE** Vishay Electro-Films



www.vishay.com



Vishay Electro-Films

## Vishay Electro-Films: Ceramic Thin Film LED Package

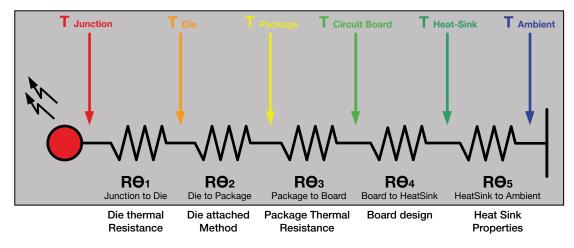
LED die performance is extremely sensitive to temperature. As junction temperature increases, LED efficiency drops. The lifetime of the LED is reduced and the overall flux of light emitted from the LED declines.

The typical efficiency of high-power LEDs is ~10 %. The remaining 90 % of the energy is dissipated as heat within the LED die. The rate by which this heat can be transferred away from the die determines the steady-state operating junction temperature and therefore determines the efficiency and reliability of the component.

Thermal management is one of the biggest challenges facing LED-based light fixture designers. Vishay Electro-Films meets this challenge by utilizing its mature thermal-management solutions, which include the following capabilities:

- Thermally conductive Al<sub>2</sub>O<sub>3</sub> or AIN substrate material as the LED package base
- Solid-filled copper vias to provide the shortest path through the substrate to carry and spread the heat away from the die
- Thick-patterned copper films to further enhance heat transfer towards the system heat sink
- Deposited Au/Sn eutectic solder to minimize thermal resistance between the die and package
- Second-level Au bumps to support eutectic/ultrasonic die attach of edge emitting diodes
- High quality aluminum reflective surfaces for increased reflectivity

The heat path in the light fixture can be modeled as a network of thermal resistors connected in series. The image below is a schematic representation of such a network:



The total thermal resistance between the junction and ambient is the sum of these five resistors. Minimizing the total thermal resistance is achieved by independently minimizing each of the five elements in the network. High-power LED packages are measured by their ability to facilitate low thermal resistance die attach techniques (minimizing RO2) and their ability to effectively carry the heat from the die to the next level of assembly (minimizing RO3).

Utilizing Vishay EFI's mature capabilities listed above allows designers to achieve both goals by facilitating high-temperature die attach (Au/Sn solder), shortening the transfer path (solid filled vias), and the use of low thermal resistance materials (thick copper patterns on ceramic substrates).

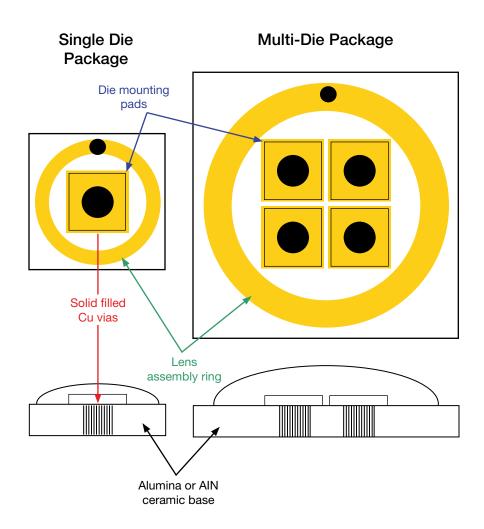
Vishay EFI has developed the LSUB as a standard ceramic submount for high-power LEDs. Samples of these parts are available upon request. Submounts can also be designed for specific applications.

Packages can be delivered in die form in waffle packs, or in wafer form to support automated assembly. Alumina substrates can be supplied with laser scoring for manual break after assembly.

Typical Applications

- High brightness LED package
- Surface-mount LED package
- Packaging solutions for single chip and multi-chip packages
- General illumination, automotive lighting, and LCD backlighting

### High-Brightness, High-Power LED packages



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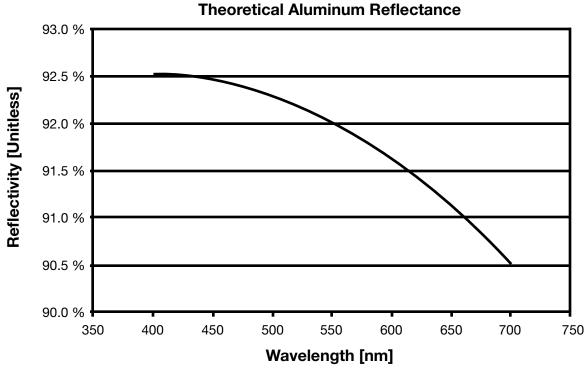
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Ceramic Material Selection					
Material	Surface finish [μ" (μm)]	Standard thickness [mils (mm)]	Thermal conductivity @ 25 °C [W/mK]	CTE [ppm/°C]	Max substrate size [in (cm)]*
Alumina (96 %)	< 35 (0.89)	15 (0.381), 25 (0.635)	25	8.2	4.5 (11.43) x 4.5 (11.43)
Alumina (99.6 %)	< 4 (0.1)	15 (0.381), 25 (0.635)	35	8.4	4.5 (11.43) x 4.5 (11.43)
AIN	< 20 (0.5)	15 (0.381), 25 (0.635)	170	4.6	4.5 (11.43) x 4.5 (11.43)

\*- Actual usable area is smaller than substrate size.

Standard Metallization					
Adhesion [Å]	Conductor [μ" (μm)]	Barrier [μ" (μm)]	Interface [μ" (μm)]	Reflector [KÅ] (optional)	
Cr	Cu	Ni	Au	AI	
750 ± 250	750 (19.05) min to 2000 (50.8) min	50 (1.27) min	50 (1.27) min	12 min	

Aluminum surfaces allow high reflectivity throughout the visible spectrum.



E.D. Palk, Handbook of Optical Constants in Solids, Academic Press, 1997

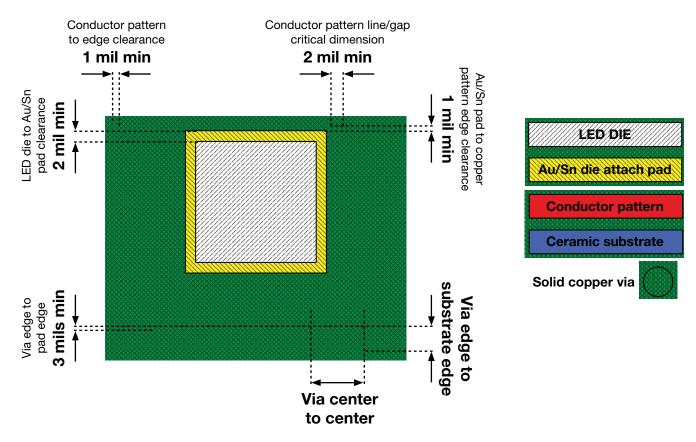
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Solid Filled Vias					
Substrate thickness [mil (mm)]	Cu filled via thermal conductivity	Via diameter [mil (mm)]	Via center to center	Via edge to circuit edge	Via edge to pad edge [mil (mm)]
15 (0.381)	375 W/mK	8 (0.203) to 23 (0.584)	2 x via diameter	1.5 x via diameter	3 (0.075)
25 (0.635)	375 W/mK	13 (0.330) to 38 (0.965)	2 x via diameter	1.5 x via diameter	3 (0.075)

Vishay EFI's unique via filling technology enables the use of bulk copper with typical thermal conductivity greater than 375 W/mK.

Deposited 80/20 Au/Sn					
Solder	Thickness [µm]	Reflow temp [°C]	Solder bleed		
80/20 Au/Sn	2 to 8 ± 1	280 to 285	None		

## **Layout Guidelines**



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## **Design Notes**

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The package can be custom designed to meet the needs of specific applications based on the design rules presented above and the general documents listed below.

HDI Design guidelines: www.vishay.com/doc?49387 Integrated Microelectronic Interconnect Circuitry: www.vishay.com/doc?61082

If your design is complete and you would like us to use your files, or if you would like us to help finalize your design, please contact:

Vishay Electro-Films, Inc. 111 Gilbane Street Warwick, RI 02886 USA Ph: +1-401-738-9150 Fax: +1-401-738-4389 Email: EFI@Vishay.com

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#### ASIA

#### SINGAPORE

VISHAY INTERTECHNOLOGY ASIA PTE LTD. 37A TAMPINES STREET 92 #07-00 SINGAPORE 528886 PH: +65-6788-6668 FAX: +65-6788-0988

#### P.R. CHINA

VISHAY TRADING (SHANGHAI) CO., LTD. 15D, SUN TONG INFOPORT PLAZA 55 HUAI HAI WEST ROAD SHANGHAI 200030 P.R. CHINA PH: +86-21-5258 5000 FAX: +86-21-5258 7979

#### JAPAN

VISHAY JAPAN CO., LTD. MG IKENOHATA BLDG. 4F 1-2-18, IKENOHATA TAITO-KU TOKYO 110-0008 JAPAN PH: +81-3-5832-6210 FAX: +81-3-5832-6260

# Build Vishay into your Design

#### EUROPE

**GERMANY** VISHAY ELECTRONIC GMBH GEHEIMRAT-ROSENTHAL-STR. 100

95100 SELB GERMANY PH: +49-9287-71-0 FAX: +49-9287-70435

#### FRANCE

VISHAY S.A. 199, BLVD DE LA MADELEINE 06003 NICE, CEDEX 1 FRANCE PH: +33-4-9337-2727 FAX: +33-4-9337-2726

#### UNITED KINGDOM

VISHAY LTD. SUITE 6C, TOWER HOUSE ST. CATHERINE'S COURT SUNDERLAND ENTERPRISE PARK SUNDERLAND SR5 3XJ UNITED KINGDOM PH: +44-191-516-8584 FAX: +44-191-549-9556